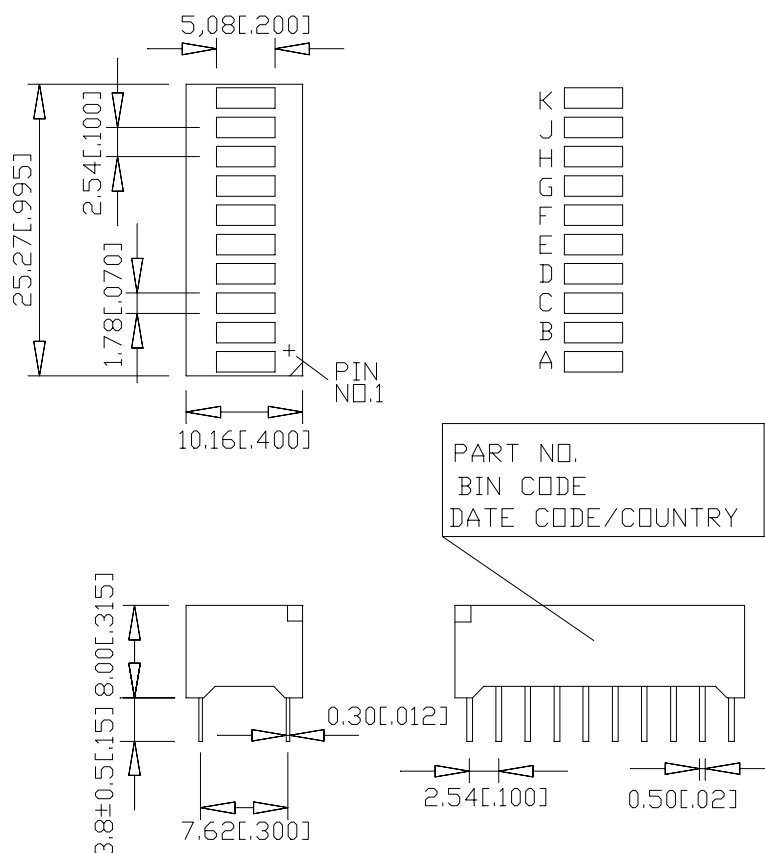
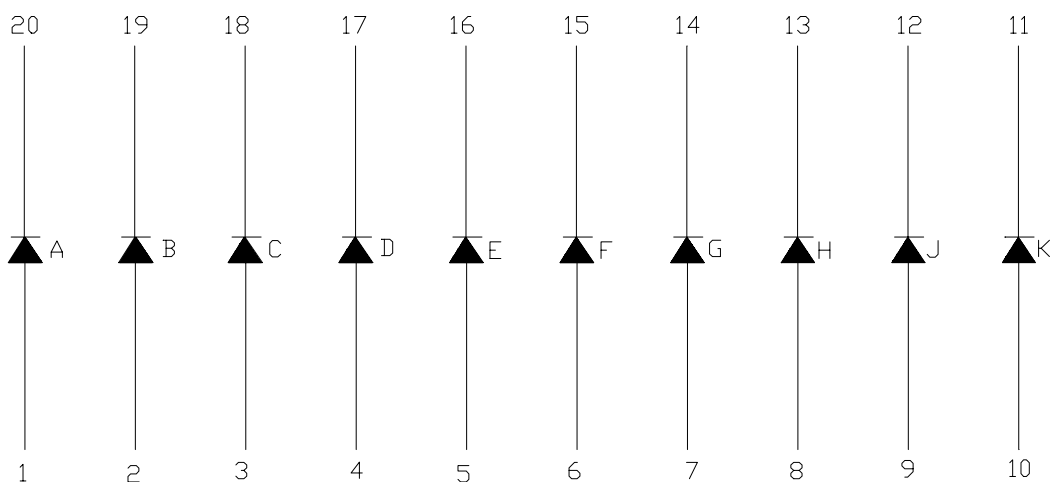


PACKAGE DIMENSIONS



NOTES: All dimensions are in millimeters. Tolerances are ± 0.25 mm (0.01") unless otherwise noted.

INTERNAL CIRCUIT DIAGRAM



ABSOLUTE MAXIMUM RATING AT Ta=25°C

PARAMETER	MAXIMUM RATING	UNIT
Power Dissipation Per Segment	60	mW
Peak Forward Current Per Segment (1/10 Duty Cycle, 0.1ms Pulse Width)	80	mA
Continuous Forward Current Per Segment	20	mA
Derating Linear From 25°C Per Segment	0.27	mA/°C
Reverse Voltage Per Segment	5	V
Operating Temperature Range	-35°C to +85°C	
Storage Temperature Range	-35°C to +85°C	
Solder Temperature: max 260°C for max 3sec at 1.6mm below seating plane.		

ELECTRICAL / OPTICAL CHARACTERISTICS AT Ta=25°C

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITION
Average Luminous Intensity	I _v	540	2000		μcd	I _F =10mA
Peak Emission Wavelength	λ _p		585		nm	I _F =20mA
Spectral Line Half-Width	Δλ		35		nm	I _F =20mA
Dominant Wavelength	λ _d		588		nm	I _F =20mA
Forward Voltage Per Segment	V _F		2.1	2.6	V	I _F =20mA
Reverse Current Per Segment	I _R			100	μA	V _R =5V
Luminous Intensity Matching Ratio	I _v -m			2:1		I _F =10mA

Note: Luminous intensity is measured with a light sensor and filter combination that approximates the CIE (Commision Internationale De L'Eclairage) eye-response curve.